

# MR36V04G54S

128M-Word × 32-Bit Page Mode **P2ROM**

## FEATURES

128Mx32 or 256Mx16-bit  
electrically switchable configuration

- Page size of 8-word x 32-Bit or 16-word x 16-Bit
- 3.0 V to 3.6 V power supply
- Random Access time 130 ns MAX
- Page Access time 25 ns MAX
- Operating current 100 mA MAX
- Standby current 85 mA MAX
- Input/Output TTL compatible
- Three-state output

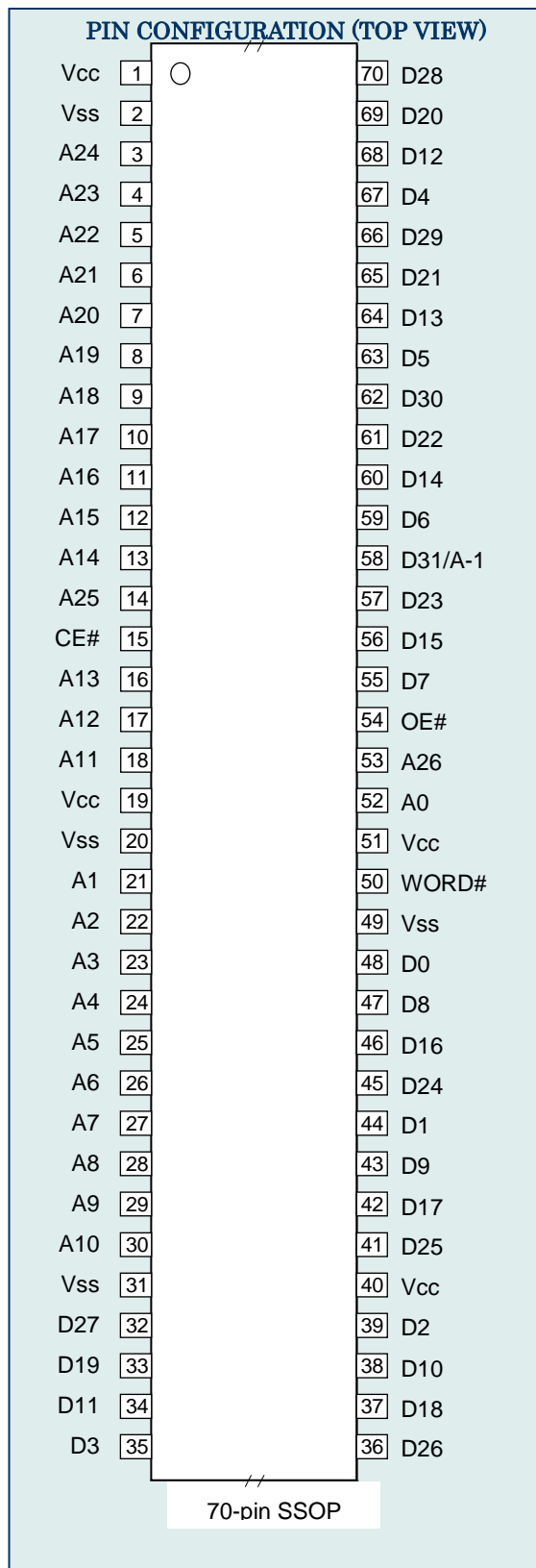
## PACKAGES

- 70-pin plastic SSOP (P-SSOP70-500-0.80-EK-MC)

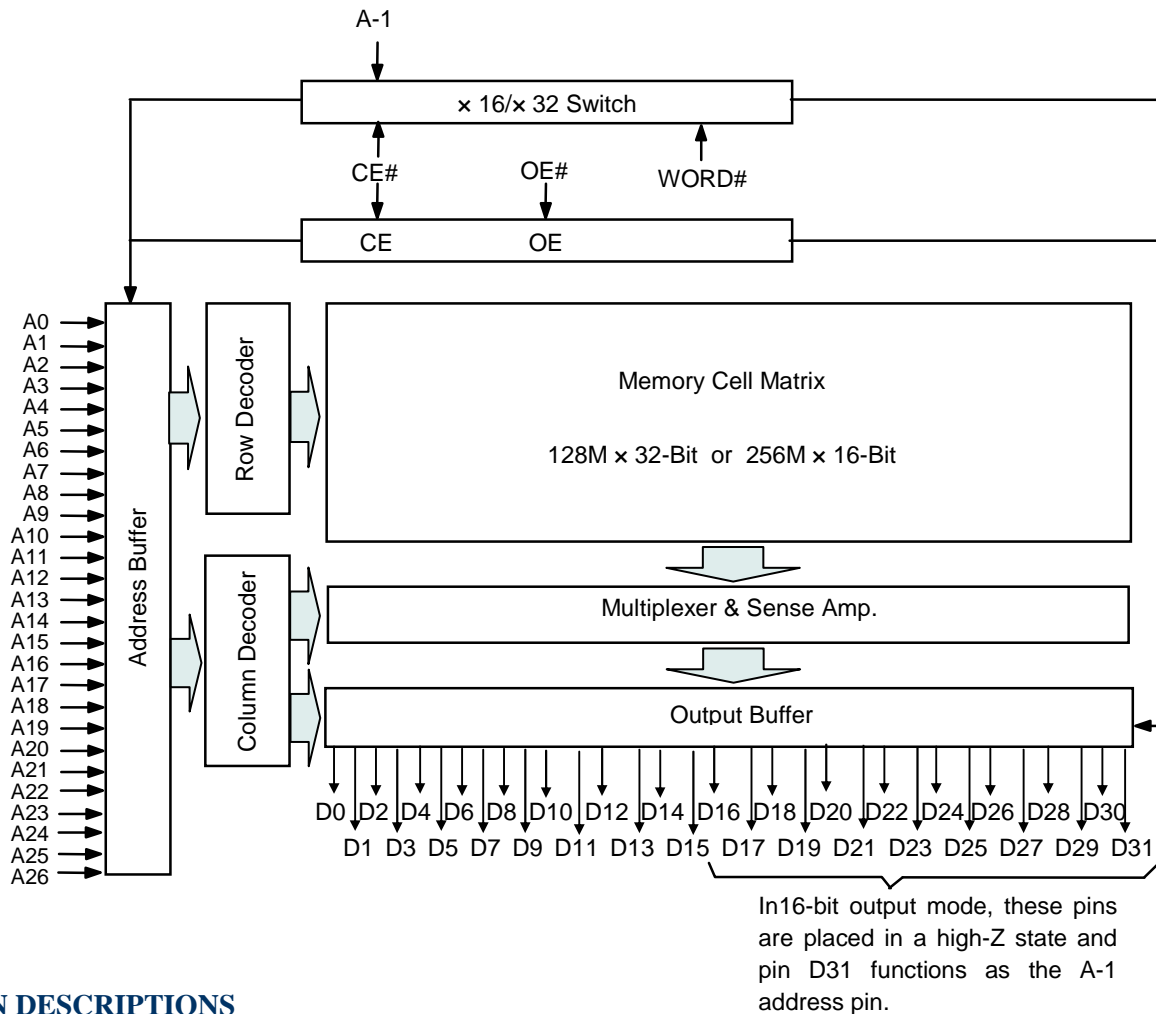
## P2ROM ADVANCED TECHNOLOGY

P2ROM stands for Production Programmed ROM. This exclusive LAPIS Semiconductor technology utilizes factory test equipment for programming the customers code into the P2ROM prior to final production testing. Advancements in this technology allows production costs to be equivalent to MASKROM and has many advantages and added benefits over the other non-volatile technologies, which include the following;

- **Short lead time**, since the P2ROM is programmed at the final stage of the production process, a large P2ROM inventory "bank system" of un-programmed packaged products are maintained to provide an aggressive lead-time and minimize liability as a custom product.
- **No mask charge**, since P2ROMs do not utilize a custom mask for storing customer code, no mask charges apply.
- **No additional programming charge**, unlike Flash and OTP that require additional programming and handling costs, the P2ROM already has the code loaded at the factory with minimal effect on the production throughput. The cost is included in the unit price.
- **Custom Marking is** available at no additional charge.



## BLOCK DIAGRAM



## PIN DESCRIPTIONS

Pin name	Functions
A0 to A26	Address inputs
D31/ A-1	Data outputs /Address -1 input
D0 to D30	Data outputs
CE#	Chip enable input
OE#	Output enable input
WORD#	Word -Byte select input
V <sub>CC</sub>	Power supply voltage
V <sub>SS</sub>	Ground

## FUNCTION TABLE

Mode	CE#	OE#	WORD#	V <sub>CC</sub>	D0 to D15	D16 to D30	D31/A-1
Read (32-Bit)	L	L	H	3.3 V	D <sub>OUT</sub>		D <sub>OUT</sub>
Read (16-Bit)	L	L	L		D <sub>OUT</sub>	Hi-Z	L/H
Output disable	L	H	H		Hi-Z		*
			L				
Standby	H	*	H		Hi-Z		*
			L				

\*: Don't Care (H or L)

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Value	Unit
Operating temperature under bias	T <sub>a</sub>	—	0 to 70	°C
Storage temperature	T <sub>stg</sub>		-55 to 125	°C
Input voltage	V <sub>I</sub>	relative to V <sub>SS</sub>	-0.5 to V <sub>CC</sub> +0.5	V
Output voltage	V <sub>O</sub>		-0.5 to V <sub>CC</sub> +0.5	V
Power supply voltage	V <sub>CC</sub>		-0.5 to 4.6	V
Output short circuit current	I <sub>OS</sub>	—	10	mA
Power dissipation per package	P <sub>D</sub>	T <sub>a</sub> =25°C	1.0	W

## RECOMMENDED OPERATING CONDITIONS

(T<sub>a</sub> = 0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
V <sub>CC</sub> power supply voltage	V <sub>CC</sub>	V <sub>CC</sub> = 3.0 to 3.6 V	3.0	—	3.6	V
Input "H" level	V <sub>IH</sub>		2.2	—	V <sub>CC</sub> +0.5*	V
Input "L" level	V <sub>IL</sub>		-0.5**	—	0.6	V

Voltage is relative to V<sub>SS</sub>.\* : V<sub>CC</sub>+1.5V(Max.) when pulse width of overshoot is less than 10ns.

\*\* : -1.5V(Min.) when pulse width of undershoot is less than 10ns.

## PIN CAPACITANCE

(V<sub>CC</sub> = 3.3 V, T<sub>a</sub> = 25°C, f = 1 MHz)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input(except Word#)	C <sub>IN1</sub>	V <sub>I</sub> = 0 V	—	—	20	pF
Output	C <sub>OUT</sub>	V <sub>O</sub> = 0 V	—	—	20	pF

## ELECTRICAL CHARACTERISTICS

### DC Characteristics

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	$I_{LI}$	$V_I = 0 \text{ to } V_{CC}$	—	—	20	$\mu\text{A}$
Output leakage current	$I_{LO}$	$V_O = 0 \text{ to } V_{CC}$	—	—	20	$\mu\text{A}$
$V_{CC}$ power supply current (Standby)	$I_{CCSC}$	CE# = Add. = $V_{CC}$ $V_{CC}=3.6\text{V}$	—	—	85	mA
$V_{CC}$ power supply current (Read)	$I_{CCA1}$	CE# = $V_{IL}$ OE# = $V_{IH}$ $t_c = 200 \text{ ns}$	—	—	100	mA
Input "H" level	$V_{IH}$	—	2.2	—	$V_{CC}+0.5^*$	V
Input "L" level	$V_{IL}$	—	-0.5**	—	0.6	V
Output "H" level	$V_{OH}$	$I_{OH} = -2 \text{ mA}$	2.4	—	—	V
Output "L" level	$V_{OL}$	$I_{OL} = 2 \text{ mA}$	—	—	0.4	V

Voltage is relative to  $V_{SS}$ .

\* :  $V_{CC}+1.5\text{V}(\text{Max.})$  when pulse width of overshoot is less than 10ns.

\*\* :  $-1.5\text{V}(\text{Min.})$  when pulse width of undershoot is less than 10ns.

### AC Characteristics

( $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ ,  $T_a = 0 \text{ to } 70^\circ\text{C}$ )

Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	$t_c$	—	130	—	ns
Address access time	$t_{ACC}$	—	—	130	ns
Address skew time	$t_{ASK}$	—	—	10	ns
CE Address skew time	$T_{CSK}$	—	—	10	ns
Page cycle time	$t_{PC}$	—	25	—	ns
Page access time	$t_{PAC}$	CE# = OE# = $V_{IL}$	—	25	ns
CE# access time	$t_{CE}$	OE# = $V_{IL}$	—	130	ns
OE# access time	$t_{OE}$	CE# = $V_{IL}$	—	25	ns
Output disable time	$t_{CHZ}$	OE# = $V_{IL}$	0	20	ns
	$t_{OHZ}$	CE# = $V_{IL}$	0	20	ns
Output hold time	$t_{OH}$	CE# = OE# = $V_{IL}$	0	—	ns

#### Measurement conditions

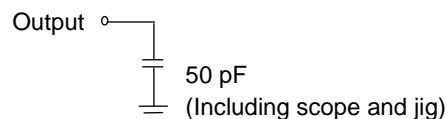
Input signal level----- 0 V/3 V

Input timing reference level ----- 1/2 $V_{CC}$

Output load ----- 50 pF

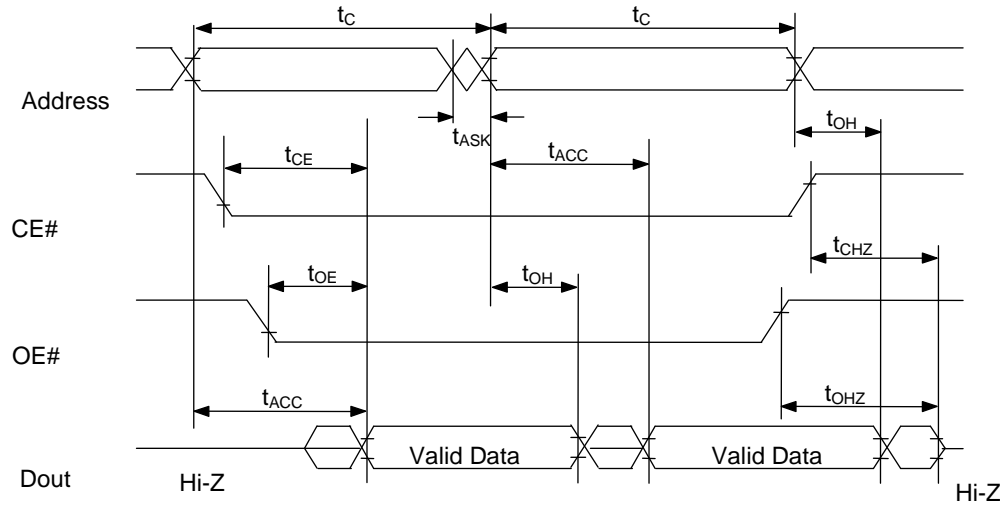
Output timing reference level----- 1/2 $V_{CC}$

#### Output load

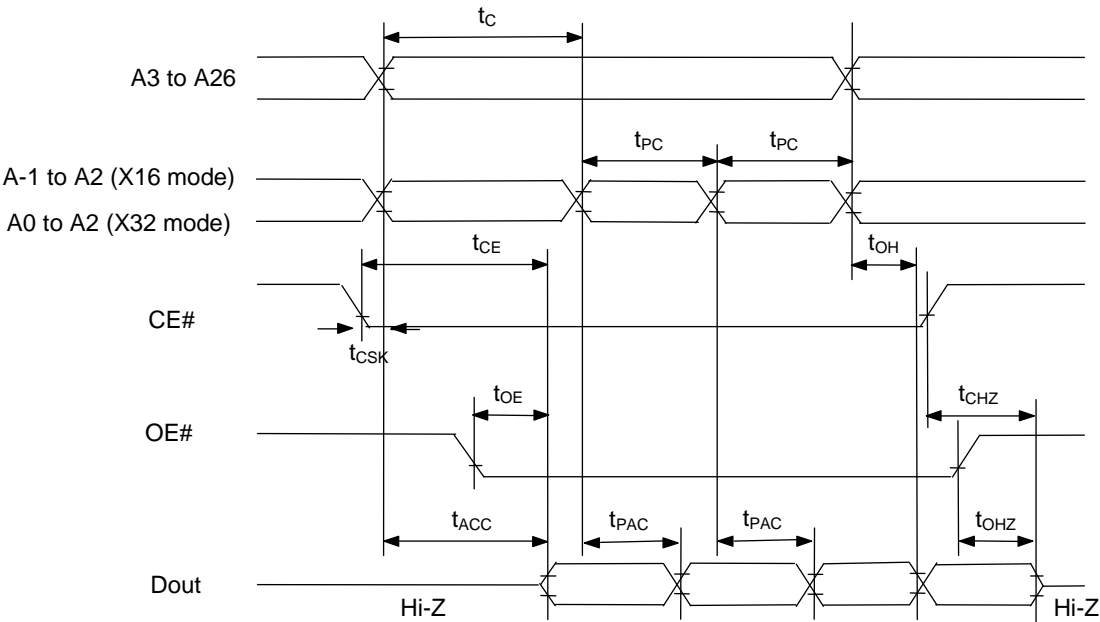


# TIMING CHART (READ CYCLE)

## Random Access Mode Read Cycle

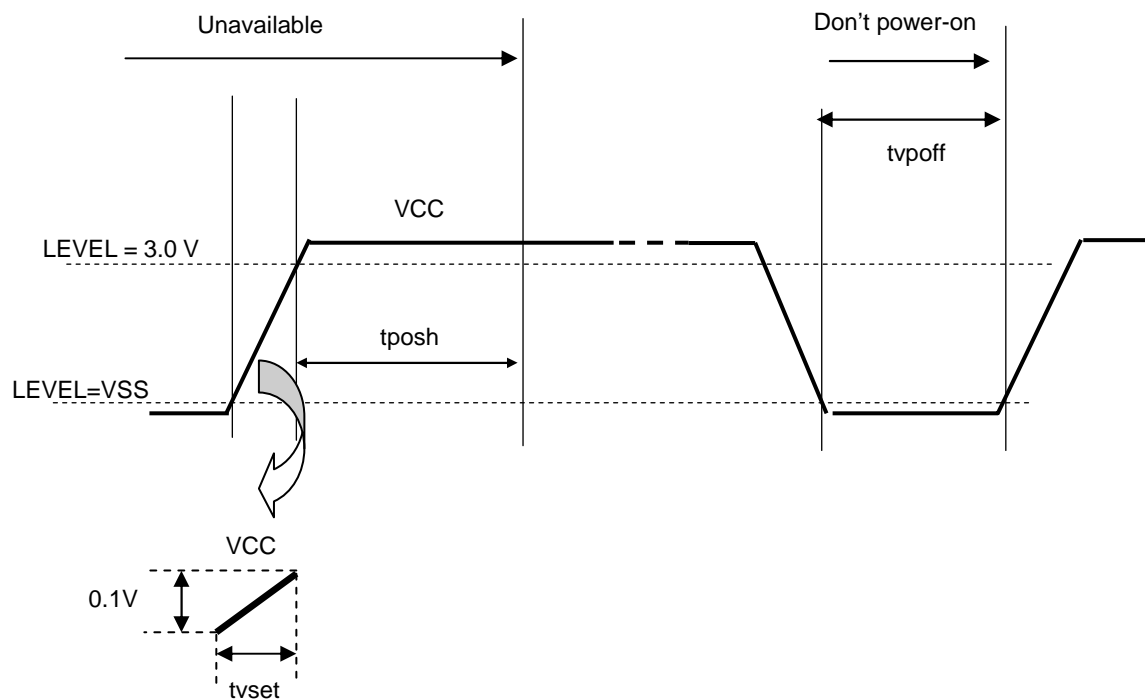


## Page Access Mode Read Cycle



**POWER ON CHARACTERISTICS** $(V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}, T_a = 0\text{ to }70^\circ\text{C})$ 

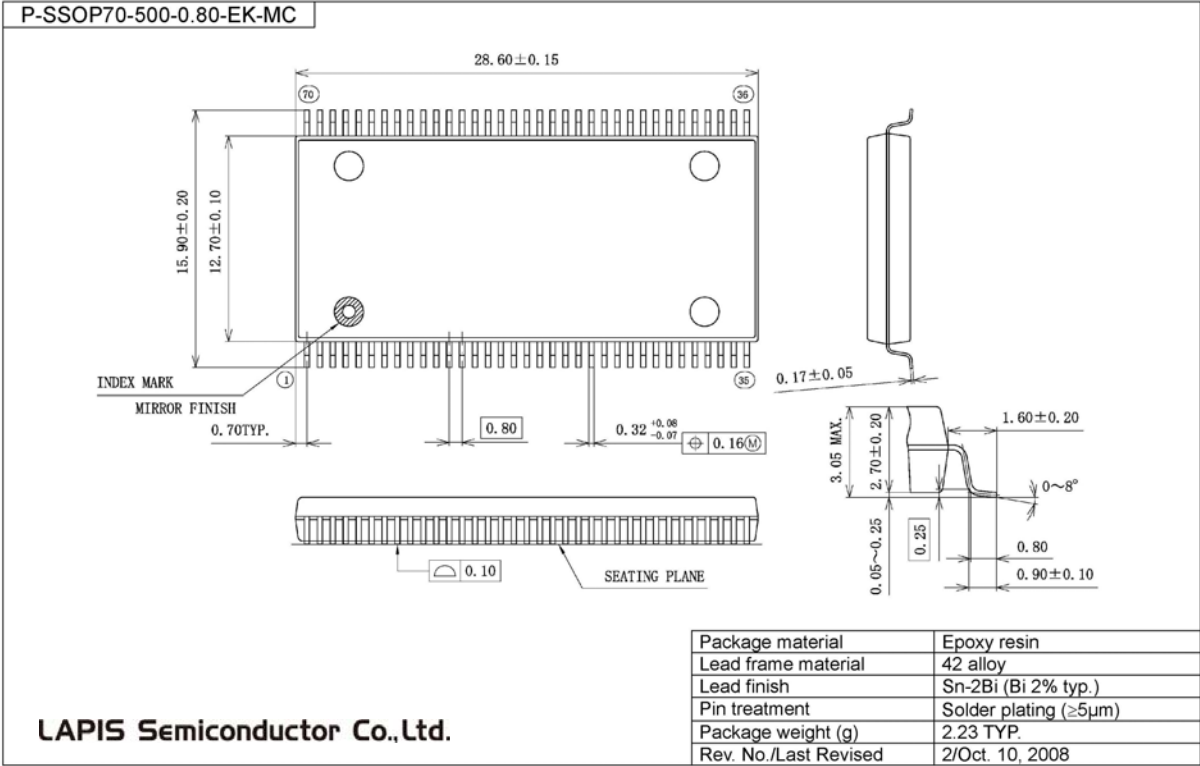
Parameter	Symbol	Condition	Min.	Max.	Unit
VCC set up time	tvset	—	5	270	us
Power on sequence hold time	tposh	—	1	—	ms
Power off hold time	tpoff	—	1	—	ms

**TIMING CHART (POWER ON)**

Note: A start-up delay of 1ms is required after power-on.  
 If you power-off VCC ,you must wait 1ms to power-on.  
 CE# must be HIGH while VCC power on sequence.

PACKAGE DIMENSIONS

(Unit: mm)



Notes for Mounting the Surface Mount Type Package

The surface mount type packages are very susceptible to heat in reflow mounting and humidity absorbed in storage.

Therefore, before you perform reflow mounting, contact ROHM’s responsible sales person for the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).

**REVISION HISTORY**

Document No.	Date	Page		Description
		Previous Edition	Current Edition	
FEDR36V04G54S-002-01	Aug.01.2009	–	–	Final edition 1



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